

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2	("5438210").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/08/04 11:20
S2	1	semiconductor and (silicon near4 substrate) and (insulat\$4 or oxide or dielectric) and diode and (semiconductor near4 region) and dop\$4 and concentration and (charge near4 carrier) and radiat\$4 and (band near4 gap) and quantum and locos and epitaxy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 11:27